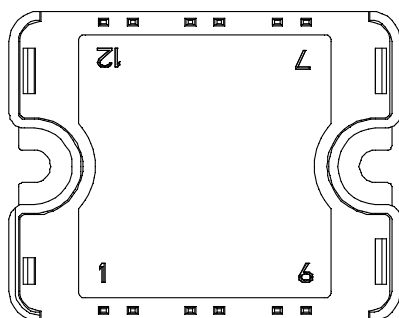
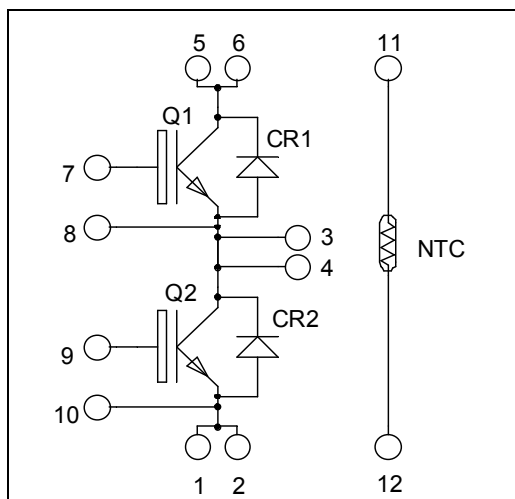


**Phase leg**  
**High speed Trench + Field Stop IGBT4**  
**Power Module**

**$V_{CES} = 650V$**   
 **$I_C = 100A @ T_c = 60^\circ C$**



Pins 3/4 must be shorted together

**Application**

- Welding converters
- Switched Mode Power Supplies
- Uninterruptible Power Supplies
- Motor control

**Features**

- **High speed Trench + Field Stop IGBT 4**
  - Low voltage drop
  - Low leakage current
  - Low switching losses
- Very low stray inductance
- Internal thermistor for temperature monitoring

**Benefits**

- Outstanding performance at high frequency operation
- Direct mounting to heatsink (isolated package)
- Low junction to case thermal resistance
- Solderable terminals both for power and signal for easy PCB mounting
- Low profile
- RoHS compliant

**All ratings @  $T_j = 25^\circ C$  unless otherwise specified**

**Absolute maximum ratings (per IGBT)**

Symbol	Parameter	Max ratings	Unit
$V_{CES}$	Collector - Emitter Voltage	650	V
$I_C$	Continuous Collector Current	$T_C = 25^\circ C$	A
		$T_C = 60^\circ C$	
$I_{CM}$	Pulsed Collector Current	$T_C = 25^\circ C$	270
$V_{GE}$	Gate - Emitter Voltage	$\pm 20$	V
$P_D$	Power Dissipation	350	W

 **CAUTION:** These Devices are sensitive to Electrostatic Discharge. Proper Handling Procedures Should Be Followed.

**Electrical Characteristics (per IGBT)**

Symbol	Characteristic	Test Conditions	Min	Typ	Max	Unit
$I_{CES}$	Zero Gate Voltage Collector Current	$V_{GE} = 0V, V_{CE} = 650V$			50	$\mu A$
$V_{CE(sat)}$	Collector Emitter Saturation Voltage	$V_{GE} = 15V$ $I_C = 100A$	$T_j = 25^\circ C$ $T_j = 150^\circ C$	1.4 2.2	2.3	V
$V_{GE(th)}$	Gate Threshold Voltage	$V_{GE} = V_{CE}, I_C = 1.6 mA$	4.2	5.1	5.6	V
$I_{GES}$	Gate – Emitter Leakage Current	$V_{GE} = 20V, V_{CE} = 0V$			150	nA

**Dynamic Characteristics (per IGBT)**

Symbol	Characteristic	Test Conditions	Min	Typ	Max	Unit
$C_{ies}$	Input Capacitance	$V_{GE} = 0V$		6100		pF
$C_{oes}$	Output Capacitance	$V_{CE} = 25V$		232		
$C_{res}$	Reverse Transfer Capacitance	$f = 1MHz$		180		
$Q_G$	Gate charge	$V_{GE} = 15V, I_C = 100A$ $V_{CE} = 480V$		630		nC
$T_{d(on)}$	Turn-on Delay Time	Inductive Switching (25°C) $V_{GE} = \pm 15V$ $V_{Bus} = 400V$ $I_C = 100A$ $R_G = 3.6\Omega$		19		ns
$T_r$	Rise Time			33		
$T_{d(off)}$	Turn-off Delay Time			197		
$T_f$	Fall Time			21		
$T_{d(on)}$	Turn-on Delay Time	Inductive Switching (150°C) $V_{GE} = \pm 15V$ $V_{Bus} = 400V$ $I_C = 100A$ $R_G = 3.6\Omega$		19		ns
$T_r$	Rise Time			29		
$T_{d(off)}$	Turn-off Delay Time			227		
$T_f$	Fall Time			22		
$E_{on}$	Turn on Energy	$V_{GE} = \pm 15V$ $V_{Bus} = 400V$ $I_C = 100A$ $R_G = 3.6\Omega$	$T_j = 150^\circ C$	2.4		mJ
$E_{off}$	Turn off Energy		$T_j = 150^\circ C$	2		
$R_G$	Integrated gate resistor			2		$\Omega$
$I_{sc}$	Short Circuit data	$V_{GE} \leq 15V ; V_{Bus} = 400V$ $t_p \leq 5\mu s ; T_j = 150^\circ C$		700		A
$R_{thJC}$	Junction to Case Thermal Resistance				0.44	$^\circ C/W$

**Diode ratings and characteristics (per diode)**

Symbol	Characteristic	Test Conditions	Min	Typ	Max	Unit
$V_{RRM}$	Peak Repetitive Reverse Voltage				650	V
$I_{RM}$	Reverse Leakage Current	$V_R = 650V$			50	$\mu A$
$I_F$	DC Forward Current	$T_c = 25^\circ C$		100		A
$V_F$	Diode Forward Voltage	$I_F = 100A$ $V_{GE} = 0V$	$T_j = 25^\circ C$ $T_j = 150^\circ C$	1.6 1.5	2	V
$t_{rr}$	Reverse Recovery Time	$I_F = 100A$ $V_R = 300V$ $di/dt = 2000A/\mu s$	$T_j = 25^\circ C$ $T_j = 150^\circ C$	125 220		ns
$Q_{rr}$	Reverse Recovery Charge		$T_j = 25^\circ C$ $T_j = 150^\circ C$	4.7 9.9		$\mu C$
$E_{rr}$	Reverse Recovery Energy		$T_j = 25^\circ C$ $T_j = 150^\circ C$	1.1 2.4		mJ
$R_{thJC}$	Junction to Case Thermal Resistance				0.77	$^\circ C/W$

**Temperature sensor NTC** (see application note APT0406 on [www.microsemi.com](http://www.microsemi.com)).

Symbol	Characteristic	Min	Typ	Max	Unit
R <sub>25</sub>	Resistance @ 25°C		50		kΩ
ΔR <sub>25</sub> /R <sub>25</sub>			5		%
B <sub>25/85</sub>	T <sub>25</sub> = 298.15 K		3952		K
ΔB/B	T <sub>C</sub> = 100°C		4		%

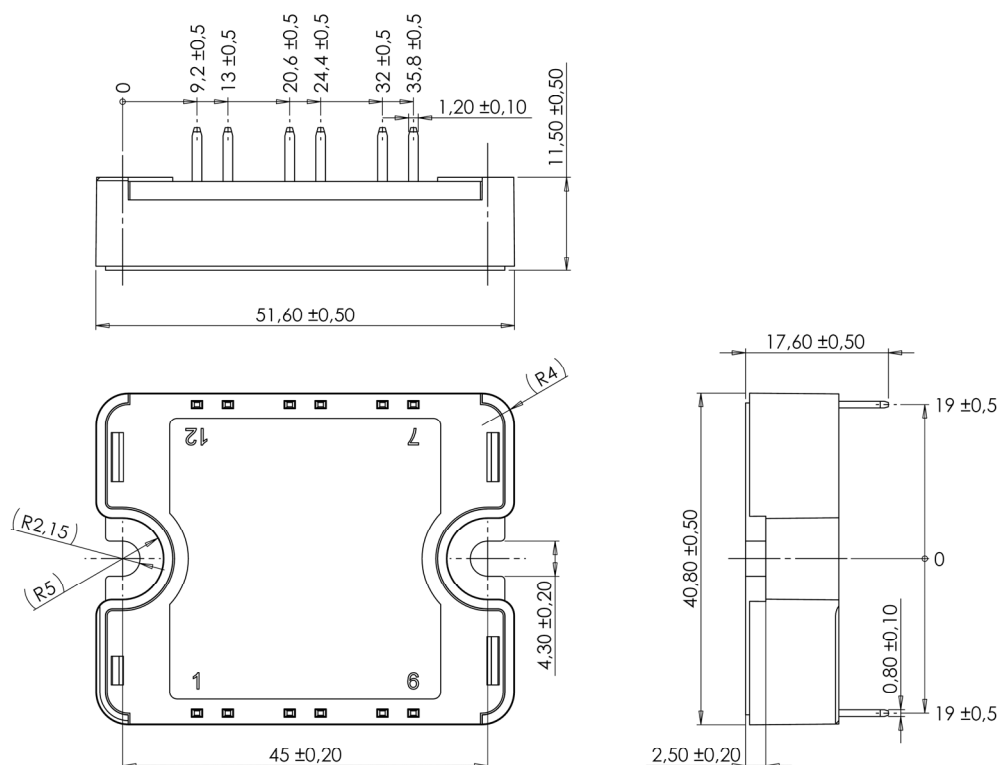
$$R_T = \frac{R_{25}}{\exp \left[ B_{25/85} \left( \frac{1}{T_{25}} - \frac{1}{T} \right) \right]}$$

T: Thermistor temperature  
R<sub>T</sub>: Thermistor value at T

### Thermal and package characteristics

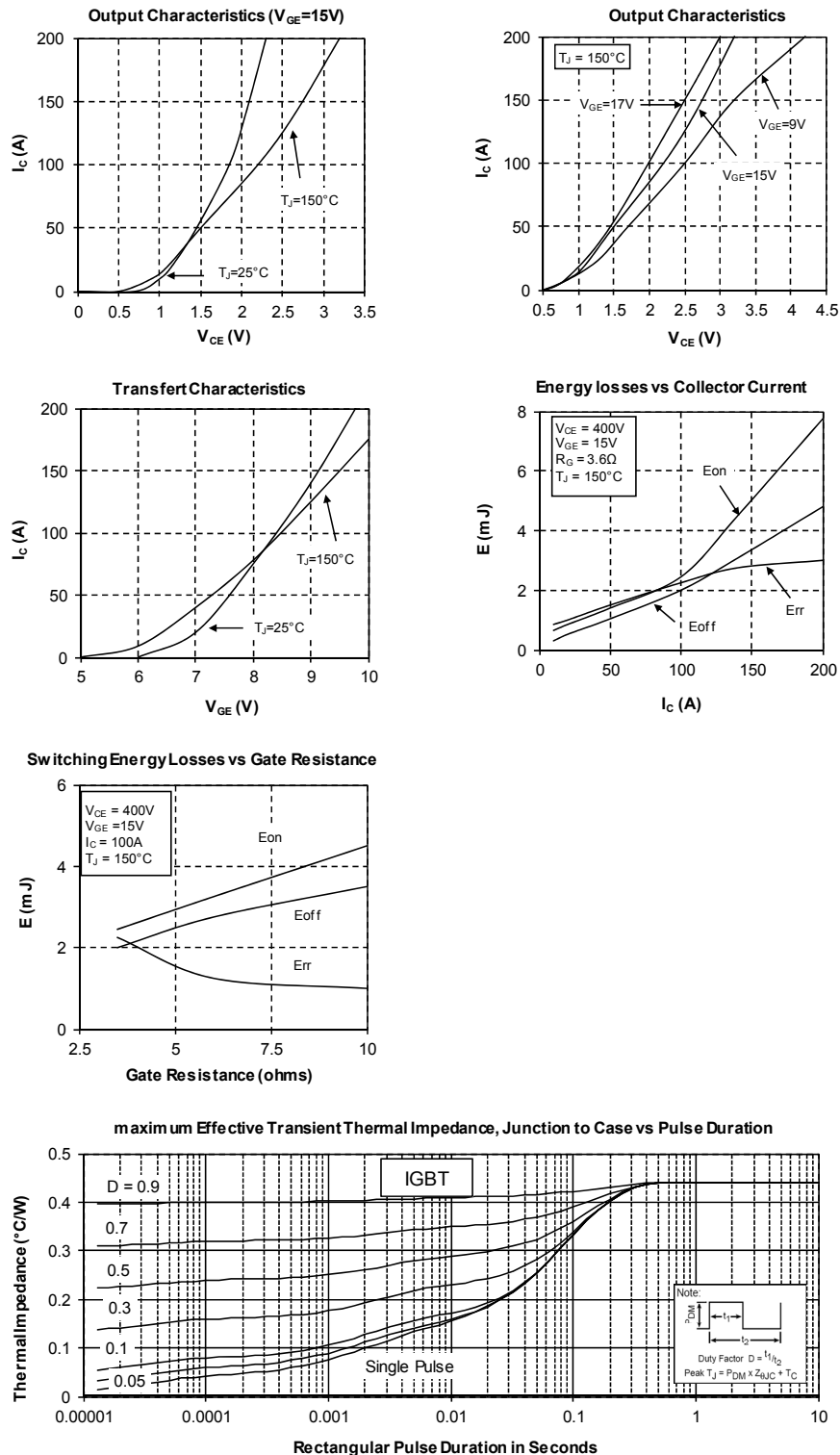
Symbol	Characteristic	Min	Max	Unit
V <sub>ISOL</sub>	RMS Isolation Voltage, any terminal to case t = 1 min, 50/60Hz	4000		V
T <sub>J</sub>	Operating junction temperature range	-40	175	°C
T <sub>JOP</sub>	Recommended junction temperature under switching conditions	-40	T <sub>Jmax</sub> -25	
T <sub>STG</sub>	Storage Temperature Range	-40	125	
T <sub>C</sub>	Operating Case Temperature	-40	125	
Torque	Mounting torque	To heatsink	M4	
Wt	Package Weight		80	g

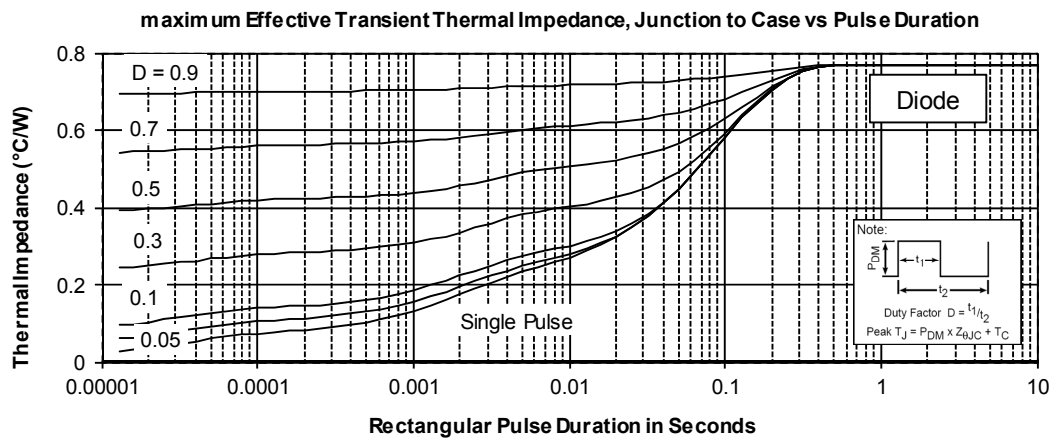
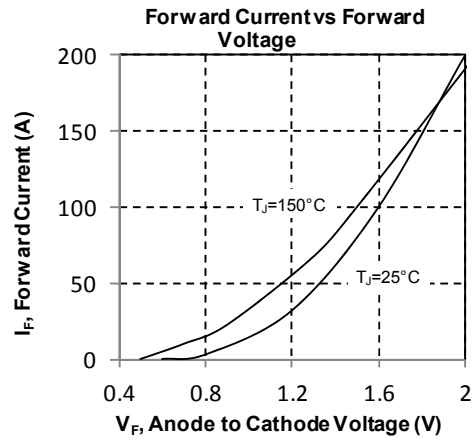
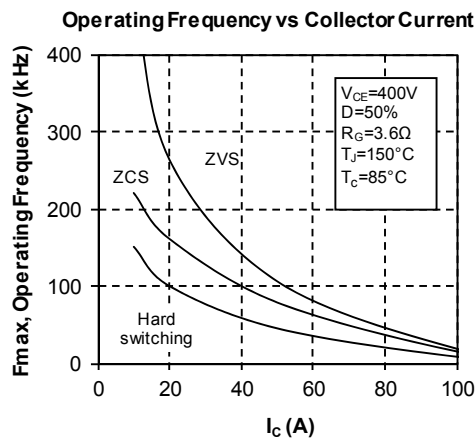
### Package outline (dimensions in mm)



See application note 1904 - Mounting Instructions for SP1 Power Modules on [www.microsemi.com](http://www.microsemi.com)

**Typical performance curve**





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